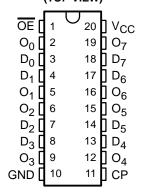
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- Function and Pinout Compatible With FCT and F Logic
- 25-Ω Output Series Resistors to Reduce Transmission-Line Reflection Noise
- Reduced V_{OH} (Typically = 3.3 V) Version of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- 3-State Outputs
- 12-mA Output Sink Current
 15-mA Output Source Current
- Edge-Triggered D-Type Inputs
- 250-MHz Typical Switching Rate

SN74FCT2374T . . . Q OR SO PACKAGE (TOP VIEW)



description

The CY74FCT2374T is a high-speed, low-power, octal D-type flip-flop featuring separate D-type inputs for each flip-flop. On-chip termination resistors at the outputs reduce system noise caused by reflections. The CY74FCT2374T can replace the CY74FCT374T to reduce noise in an existing design. The device has 3-state outputs for bus-oriented applications. A buffered clock (CP) and output-enable (\overline{OE}) inputs are common to all flip-flops. The flip-flops in the CY74FCT2374T store the state of their individual data (D) inputs that meet the setup-time and hold-time requirements on the low-to-high CP transition. When \overline{OE} is low, the contents of the flip-flops are available at the outputs. When \overline{OE} is high, the outputs are in the high-impedance state. The state of \overline{OE} does not affect the state of the flip-flops.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

TA	PACKAGE†		PACKAGE†		PACKAGE [†] SPEED ORDERABI (ns) PART NUMB		TOP-SIDE MARKING
QSOP - Q		Tape and reel	5.2	CY74FCT2374CTQCT	FCT2374C		
	SOIC - SO	Tube	5.2	CY74FCT2374CTSOC	FCT2374C		
		Tape and reel	5.2	CY74FCT2374CTSOCT	10123740		
–40°C to 85°C	QSOP – Q	Tape and reel	6.5	CY74FCT2374ATQCT	FCT2374A		
-40 C to 85 C	SOIC - SO	Tube	6.5	CY74FCT2374ATSOC	FCT2374A		
	3010 = 30	Tape and reel	6.5	CY74FCT2374ATSOCT	FC12374A		
	0010 00	Tube	10	CY74FCT2374TSOC	FCT2374		
	SOIC – SO	Tape and reel	10	CY74FCT2374TSOCT	FC123/4		

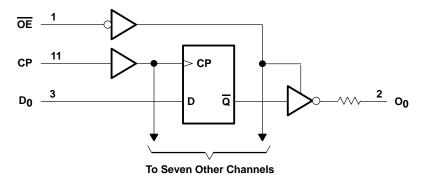
T Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

	INPUTS	OUTPUT	
D	СР	0	
Н	↑	L	Н
L	\uparrow	L	L
Х	X	Н	Z

H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance state, \uparrow = Low-to-high clock transition

logic diagram (positive logic)





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absolute maximum rating over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	0.5 V to 7 V
DC input voltage range	0.5 V to 7 V
DC output voltage range	0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ _{JA} (see Note 1): Q pac	kage 68°C/W
SO pa	ackage
Ambient temperature range with power applied, T _A	
Storage temperature range, T _{stq}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
ІОН	High-level output current			-15	mA
loL	Low-level output current			12	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
VIK	V _{CC} = 4.75 V,	$I_{IN} = -18 \text{ mA}$			-0.7	-1.2	V
VOH	$V_{CC} = 4.75 V$,	$I_{OH} = -15 \text{ mA}$		2.4	3.3		V
V _{OL}	$V_{CC} = 4.75 V$,	$I_{OL} = 12 \text{ mA}$			0.3	0.55	V
ROUT	$V_{CC} = 4.75 V$,	$I_{OL} = 12 \text{ mA}$		20	25	40	Ω
V _{hys}	All inputs				0.2		V
lį	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = V_{CC}$				5	μΑ
lн	$V_{CC} = 5.25 \text{ V},$	V _{IN} = 2.7 V			±1	μΑ	
I _{ΙL}	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 0.5 V$			±1	μΑ	
lozh	$V_{CC} = 5.25 \text{ V},$	V _{OUT} = 2.7 V			10	μΑ	
lozL	$V_{CC} = 5.25 \text{ V},$			-10	μΑ		
los [‡]	V _{CC} = 5.25 V,	VOUT = 0 V	-60	-120	-225	mA	
l _{off}	$V_{CC} = 0 V$,	V _{OUT} = 4.5 V	V _{OUT} = 4.5 V				μΑ
Icc	$V_{CC} = 5.25 \text{ V},$	$V_{IN} \le 0.2 V$,	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2	mA
Δl _{CC}	$V_{CC} = 5.25 \text{ V}, V_{IN} = 3.25 \text{ V}$	3.4 V\$, f ₁ = 0, Outputs ope	en		0.5	2	mA
I _{CCD} ¶	$\frac{V_{CC}}{OE}$ = 5.25 V, Output OE = GND, $V_{IN} \le 0.2$	ts open, One input switching V or $V_{IN} \ge V_{CC} - 0.2 \text{ V}$	ng at 50% duty cycle,		0.06	0.12	mA/ MHz
	V _{CC} = 5.25 V,	One bit switching at f ₁ = 5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{V}$		0.7	1.4	
I _C #	Outputs open,	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1.2	3.4	mA
I.C.,	$\frac{f_0}{OE} = 10 \text{ MHz},$ OE = GND	Eight bits switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$	1.6		3.2	IIIA
		at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		3.9	12.2	
C _i					5	10	pF
Co					9	12	pF

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

 $^{\#}$ IC = ICC + Δ ICC \times DH \times NT + ICCD ($f_0/2 + f_1 \times N_1$)

Where:

IC = Total supply current

ICC = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input ($V_{IN} = 3.4 \text{ V}$)

D_H = Duty cycle for TTL inputs high N_T = Number of TTL inputs at D_H

ICCD = Dynamic current caused by an input transition pair (HLH or LHL)

f₀ = Clock frequency for registered devices, otherwise zero

f₁ = Input signal frequency

N₁ = Number of inputs changing at f₁

All currents are in milliamperes and all frequencies are in megahertz.

Values for these conditions are examples of the I_{CC} formula.



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, Ios tests should be performed last.

[§] Per TTL-driven input ($V_{IN} = 3.4 \text{ V}$); all other inputs at V_{CC} or GND

[¶] This parameter is derived for use in total power-supply calculations.

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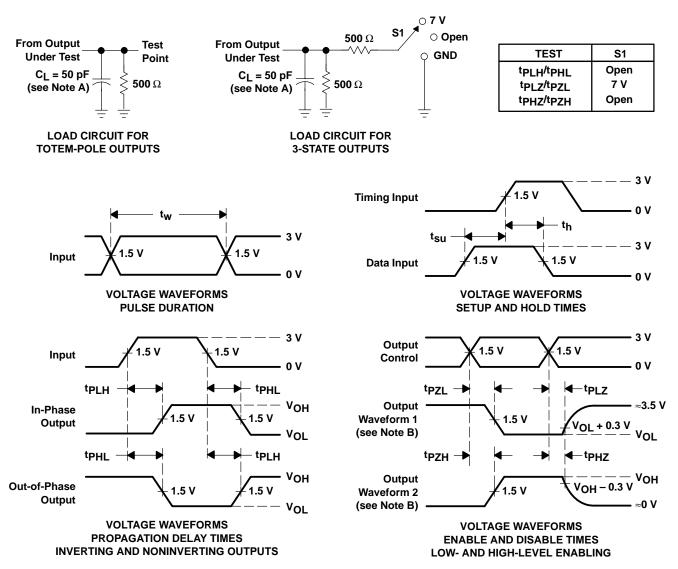
timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			Г2374Т	CY74FCT2374AT		CY74FCT2374CT		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _W	Pulse duration, CP	7		5		4		ns
t _{su}	Setup time, data before CP↑	2		2		1.5		ns
th	Hold time, data after CP↑	1.5		1.5		1		ns

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	CY74FC	CY74FCT2374T		CY74FCT2374AT		CY74FCT2374CT		
PARAMETER	(INPUT)		MIN	MAX	MIN	MAX	MIN	MAX	UNIT	
t _{PLH}	СР	0	2	10	2	6.5	2	5.2	ns	
t _{PHL}	GF	O	2	10	2	6.5	2	5.2	115	
^t PZH	ŌĒ	0	1.5	12.5	1.5	6.5	1.5	6.2		
tpZL	OE		1.5	12.5	1.5	6.5	1.5	6.2	ns	
t _{PHZ}	ŌĒ	0	1.5	8	1.5	5.5	1.5	5		
^t PLZ	OE	O	1.5	8	1.5	5.5	1.5	5	ns	

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





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PACKAGING INFORMATION

APECT2374ATSOCTE4	Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TAPECT2374CTSOCTE4	74FCT2374ATSOCTE4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI
TAFCT2374CTSOCTG4	74FCT2374ATSOCTG4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI
TAFCT2574ATQCTE4	74FCT2374CTSOCTE4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI
CSOP	74FCT2374CTSOCTG4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI
TAFCT2574ATSOCTG4	74FCT2574ATQCTE4	ACTIVE		DBQ	20	2500		CU NIPDAU	Level-2-260C-1 YEAR
No Sb/Br No Sb/Br	74FCT2574ATSOCTE4	ACTIVE	SOIC	DW	20	2000		CU NIPDAU	Level-1-260C-UNLIM
TAPECT2574CTSOCTG4	74FCT2574ATSOCTG4	ACTIVE	SOIC	DW	20	2000	,	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2374ATQCT ACTIVE QSOP SSOP/ QSOP DBQ DBQ QSOP 20 2500 QSOP Green (RoHS & no Sb/Br) CU NIPDAU Devil-2-260C-1 YEAR CY74FCT2374ATQCTG4 ACTIVE QSOP SSOP/ QSOP DBQ DBQ QSOP 20 2500 QSOP Green (RoHS & no Sb/Br) CU NIPDAU Devel-2-260C-1 YEAR CY74FCT2374ATQCTG4 ACTIVE QSOP SSOP/ QSOP DBQ DBQ DSOP 20 TBD CU NIPDAU Devel-2-260C-1 YEAR CY74FCT2374ATSOCG4 ACTIVE SOIC QSOP DW 20 TBD Call TI Call TI CY74FCT2374CTQCTG4 ACTIVE SSOP/ QSOP DBQ QSOP 20 TBD Call TI Call TI CY74FCT2374CTQCTG4 ACTIVE SSOP/ QSOP SOIC QSOP DW 20 TBD Call TI Call TI CY74FCT2374TSOCG4 ACTIVE SOIC DW 20 TBD Call TI Call TI CY74FCT2374TSOCG4 ACTIVE SOIC DW 20 TBD Call TI Call TI CY74FCT2374TSOCG4 ACTIVE SOIC SOIC DW 20 TBD Call TI Call TI CY	74FCT2574CTSOCTE4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI
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CY74FCT2574ATQCTG4 ACTIVE QSOP QSOP DBQ QSOP DBQ QSOP 20 2500 Green (ROHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br) CY74FCT2574ATSOC ACTIVE SOIC DW 20 25 Green (ROHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CU NIPDAU Level-1-260C-UNLIM Level-1-260C-UNLIM no Sb/Br) CY74FCT2574ATSOCE4 ACTIVE SOIC DW 20 25 Green (ROHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574ATSOCG4 ACTIVE SOIC DW 20 25 Green (ROHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574ATSOCT ACTIVE SOIC DW 20 2000 Green (ROHS & NO Sb/Br) CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574CTQCT ACTIVE SSOP/ QSOP DBQ 20 2500 Green (ROHS & NO Sb/Br) CU NIPDAU Level-2-260C-1 YEAR no Sb/Br) CY74FCT2574CTQCTE4 ACTIVE SSOP/ QSOP DBQ 2500 Green (ROHS & NO Sb/Br) CU NIPDAU Level-2-260C-1 YEAR NO Sb/Br)	CY74FCT2374TSOCTG4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI
CY74FCT2574ATSOC ACTIVE SOIC DW 20 25 Green (RoHS & no Sb/Br) CU NIPDAU Level-1-260C-UNLIM CY74FCT2574ATSOCE4 ACTIVE SOIC DW 20 25 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574ATSOCG4 ACTIVE SOIC DW 20 25 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574ATSOCT ACTIVE SOIC DW 20 2000 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574CTQCT ACTIVE SSOP/ QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br) CY74FCT2574CTQCTE4 ACTIVE SSOP/ QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br)	CY74FCT2574ATQCT	ACTIVE		DBQ	20	2500	,	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2574ATSOCE4 ACTIVE SOIC DW 20 25 Green (RoHS & CU NIPDAU no Sb/Br) Level-1-260C-UNLIM CY74FCT2574ATSOCG4 ACTIVE SOIC DW 20 25 Green (RoHS & CU NIPDAU no Sb/Br) Level-1-260C-UNLIM CY74FCT2574ATSOCT ACTIVE SOIC DW 20 2000 Green (RoHS & CU NIPDAU no Sb/Br) Level-1-260C-UNLIM CY74FCT2574CTQCT ACTIVE SSOP/QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU no Sb/Br) Level-2-260C-1 YEAR no Sb/Br) CY74FCT2574CTQCTE4 ACTIVE SSOP/QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU no Sb/Br) Level-2-260C-1 YEAR no Sb/Br)	CY74FCT2574ATQCTG4	ACTIVE		DBQ	20	2500		CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2574ATSOCE4 ACTIVE SOIC DW 20 25 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574ATSOCG4 ACTIVE SOIC DW 20 25 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574ATSOCT ACTIVE SOIC DW 20 20 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574CTQCT ACTIVE SSOP/ QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574CTQCTE4 ACTIVE SSOP/ QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br) CY74FCT2574CTQCTE4 ACTIVE SSOP/ QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br)	CY74FCT2574ATSOC	ACTIVE	SOIC	DW	20	25	`	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2574ATSOCG4 ACTIVE SOIC DW 20 25 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574ATSOCT ACTIVE SOIC DW 20 2000 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574CTQCT ACTIVE SSOP/ QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br) CY74FCT2574CTQCTE4 ACTIVE SSOP/ DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br) CY74FCT2574CTQCTE4 ACTIVE SSOP/ DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br)	CY74FCT2574ATSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2574ATSOCT ACTIVE SOIC DW 20 2000 Green (RoHS & CU NIPDAU Level-1-260C-UNLIM no Sb/Br) CY74FCT2574CTQCT ACTIVE SSOP/ DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br) CY74FCT2574CTQCTE4 ACTIVE SSOP/ DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br)	CY74FCT2574ATSOCG4	ACTIVE	SOIC	DW	20	25	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2574CTQCT ACTIVE SSOP/ QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br) CY74FCT2574CTQCTE4 ACTIVE SSOP/ QSOP DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br)	CY74FCT2574ATSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2574CTQCTE4 ACTIVE SSOP/ DBQ 20 2500 Green (RoHS & CU NIPDAU Level-2-260C-1 YEAR no Sb/Br)	CY74FCT2574CTQCT	ACTIVE		DBQ	20	2500	Green (RoHS &	CU NIPDAU	Level-2-260C-1 YEAR
·	CY74FCT2574CTQCTE4	ACTIVE	SSOP/	DBQ	20	2500	Green (RoHS &	CU NIPDAU	Level-2-260C-1 YEAR
	CY74FCT2574CTQCTG4	ACTIVE		DBQ	20	2500	,	CU NIPDAU	Level-2-260C-1 YEAR

PACKAGE OPTION ADDENDUM

www.ti.com 26-Aug-2009

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
		QSOP				no Sb/Br)		
CY74FCT2574CTSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2574CTSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2574CTSOCG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2574TSOCE4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI
CY74FCT2574TSOCG4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI
CY74FCT2574TSOCTE4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI
CY74FCT2574TSOCTG4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

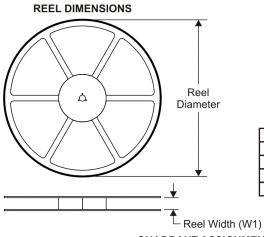
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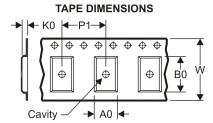
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PACKAGE MATERIALS INFORMATION

www.ti.com 29-Jul-2009

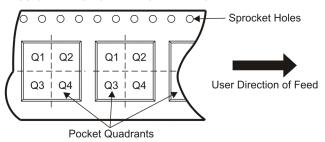
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All difficultions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT2374ATQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2574ATQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2574ATSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CY74FCT2574CTQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

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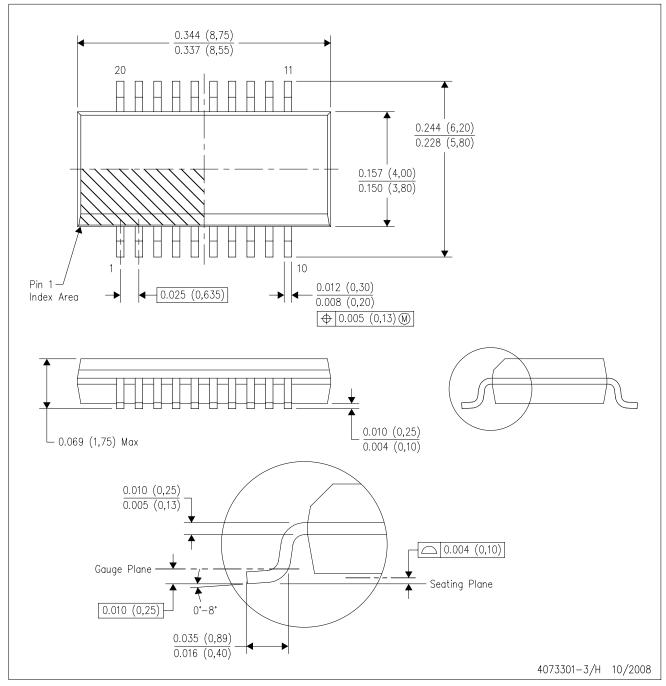


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT2374ATQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
CY74FCT2574ATQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
CY74FCT2574ATSOCT	SOIC	DW	20	2000	346.0	346.0	41.0
CY74FCT2574CTQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0

DBQ (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE

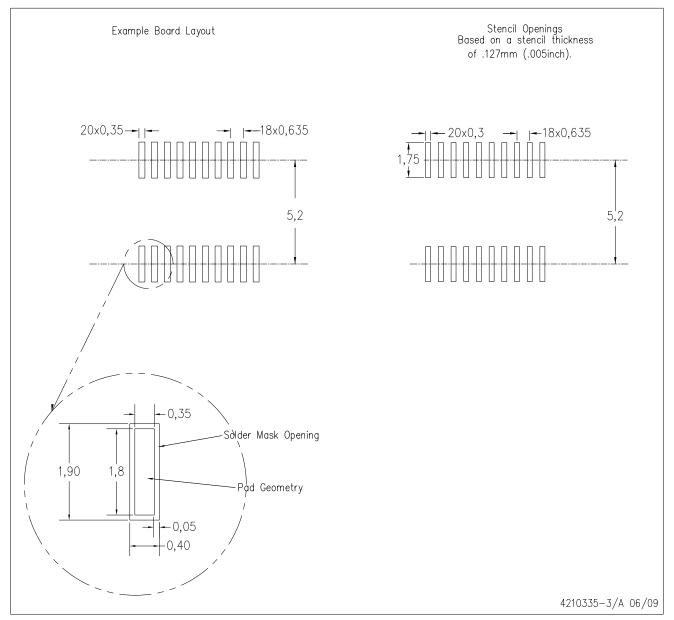


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.



DBQ (R-PDSO-G20)



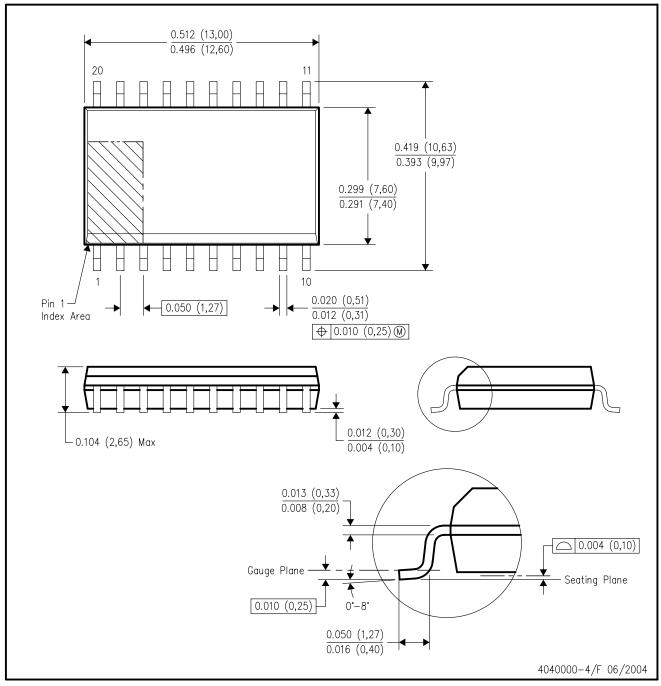
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



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